

# BCR08AS-14A

700V - 0.8A - Triac Low Power Use

R07DS0970EJ0001 Rev.0.01 Nov 28, 2012

#### **Features**

 $I_{T (RMS)} : 0.8 A$  $V_{DRM}$ : 700 V

I<sub>FGTI</sub>, I<sub>RGTI</sub>, I<sub>RGTIII</sub>: 5 mA Completed Pb Free

- Non-Insulated Type
- Planar Passivation Type
- Surface Mounted Type

#### **Outline**

RENESAS Package code: PLZZ0004CA-A) (Package name: UPAK)





- 1. T<sub>1</sub> Terminal
- 2. T<sub>2</sub> Terminal3. Gate Terminal
- 4. T<sub>2</sub> Terminal

#### **Applications**

Hybrid IC, solid state relay, electric fan, washing machine, and other general purpose control applications

### **Maximum Ratings**

Parameter	Symbol	Voltage class	Unit	
r al allietei	Cymbol	14		
Repetitive peak off-state voltage <sup>Note1</sup>	$V_{DRM}$	700	V	
Non- repetitive peak off-state voltage <sup>Note1</sup>	$V_{DSM}$	840	V	

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I <sub>T (RMS)</sub>	0.8	А	Commercial frequency, sine full wave 360° conduction, Ta = 40°C <sup>Note3</sup>
Surge on-state current	I <sub>TSM</sub>	8	А	60 Hz sinewave 1 full cycle, peak value, non-repetitive
I <sup>2</sup> t for fusing	l <sup>2</sup> t	0.26	A <sup>2</sup> s	Value corresponding to 1 cycle of half wave 60 Hz, surge on-state current
Peak gate power dissipation	$P_{GM}$	1	W	
Average gate power dissipation	P <sub>G (AV)</sub>	0.1	W	
Peak gate voltage	$V_{GM}$	6	V	
Peak gate current	I <sub>GM</sub>	0.5	Α	
Junction temperature	Tj	- 40 to +125	°C	
Storage temperature	Tstg	- 40 to +125	°C	
Mass	_	50	mg	Typical value

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#### **Electrical Characteristics**

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state cur	rent	I <sub>DRM</sub>	_	_	1.0	mA	Tj = 125°C, V <sub>DRM</sub> applied
On-state voltage		$V_{TM}$	_	_	2.0	V	$Tc = 25^{\circ}C$ , $I_{TM} = 1.2 A$ ,
							Instantaneous measurement
Gate trigger voltage <sup>Note2</sup>	I	$V_{FGTI}$		_	2.0	V	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ $\Omega$ ,
	II	$V_{RGTI}$		_	2.0	V	$R_G = 330 \Omega$
	III	$V_{RGTIII}$	_	_	2.0	V	
Gate trigger current <sup>Note2</sup>	I	$I_{\text{FGT}_{\text{I}}}$	_	_	5	mA	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ $\Omega$ ,
	II	$I_{RGT_{ m I}}$		_	5	mA	$R_G = 330 \Omega$
	III	$I_{RGTIII}$		_	5	mA	
Gate non-trigger voltage		$V_{GD}$	0.2	_	_	V	Tj = 125°C, V <sub>D</sub> = 1/2 V <sub>DRM</sub>
Thermal resistance		R <sub>th (j-a)</sub>	_	_	65	°C/W	Junction to ambiebt <sup>Note3</sup>
Critical-rate of rise of off-stat commutating voltage <sup>Note4</sup>	е	(dv/dt)c	0.5	_	_	V/μs	Tj = 125°C

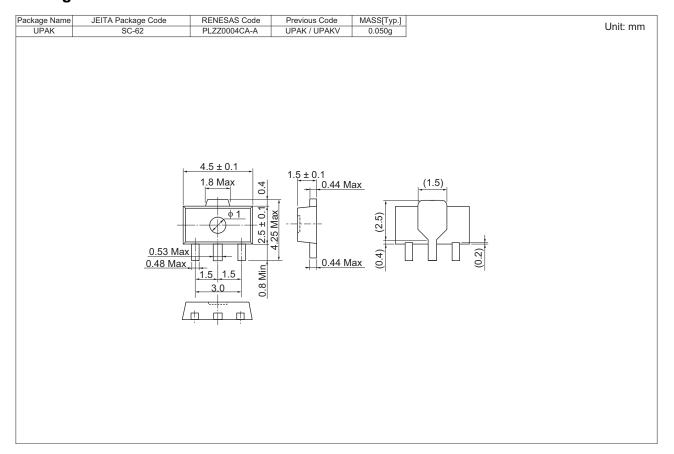
Notes: 1. Gate open.

- 2. Measurement using the gate trigger characteristics measurement circuit.
- 3. Soldering with ceramic plate (25 mm×25 mm×t0.7 mm)
- 4. Test conditions of the critical-rate of rise of off-state commutating voltage are shown in the table below.

Test conditions	Commutating voltage and current waveforms (inductive load)			
1. Junction temperature Tj = 125°C	Supply Voltage  → Time			
2. Rate of decay of on-state commutating current (di/dt)c = - 0.4 A/ms	Main Current (di/dt)c			
3. Peak off-state voltage V <sub>D</sub> = 400 V	Main Voltage Time (dv/dt)c			

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# **Package Dimensions**



# **Ordering Information**

Orderable Part Number	Packing	Quantity	Remark
BCR08AS-14AT14#B10	Embossed Tape	4000 pcs.	Taping direction "T1"

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